

August Yurgens

List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

94
papers

2,543
citations

28
h-index

49
g-index

102
ext. papers

2,714
ext. citations

3.2
avg. IF

4.83
L-index

#	Paper	IF	Citations
94	Large Responsivity of Graphene Radiation Detectors With Thermoelectric Readout: Results of Simulations. <i>Sensors</i> , 2020 , 20,	3.8	2
93	A graphene-based neutral particle detector. <i>Applied Physics Letters</i> , 2019 , 114, 061902	3.4	4
92	Making thick photoresist SU-8 flat on small substrates. <i>Journal of Micromechanics and Microengineering</i> , 2019 , 29, 017001	2	2
91	Vertically Aligned Graphene Coating is Bactericidal and Prevents the Formation of Bacterial Biofilms. <i>Advanced Materials Interfaces</i> , 2018 , 5, 1701331	4.6	47
90	Graphene bolometer with thermoelectric readout and capacitive coupling to an antenna. <i>Applied Physics Letters</i> , 2018 , 112, 063501	3.4	18
89	SINIS bolometer with a suspended absorber. <i>Journal of Physics: Conference Series</i> , 2018 , 969, 012088	0.3	1
88	Chiral charge pumping in graphene deposited on a magnetic insulator. <i>Physical Review B</i> , 2017 , 95,	3.3	19
87	Encapsulation of graphene in Parylene. <i>Applied Physics Letters</i> , 2017 , 110, 053504	3.4	14
86	Thermoelectric effects in graphene at high bias current and under microwave irradiation. <i>Scientific Reports</i> , 2017 , 7, 15542	4.9	3
85	Electrical and optical properties of a bolometer with a suspended absorber and tunneling-current thermometers. <i>Applied Physics Letters</i> , 2017 , 110, 242601	3.4	7
84	Rapid chemical vapor deposition of graphene on liquid copper. <i>Synthetic Metals</i> , 2016 , 216, 93-97	3.6	13
83	A Mechanism for Highly Efficient Electrochemical Bubbling Delamination of CVD-Grown Graphene from Metal Substrates. <i>Advanced Materials Interfaces</i> , 2016 , 3, 1500492	4.6	28
82	Ultrahigh Surface-Enhanced Raman Scattering of Graphene from Au/Graphene/Au Sandwiched Structures with Subnanometer Gap. <i>Advanced Optical Materials</i> , 2016 , 4, 2021-2027	8.1	32
81	Pore-free bubbling delamination of chemical vapor deposited graphene from copper foils. <i>Journal of Materials Chemistry C</i> , 2015 , 3, 8634-8641	7.1	28
80	Single-crystalline Bi ₂ Sr ₂ CaCu ₂ O _{8+x} detectors for direct detection of microwave radiation. <i>Applied Physics Letters</i> , 2015 , 106, 152601	3.4	3
79	Measurements of weak localization of graphene in inhomogeneous magnetic fields. <i>JETP Letters</i> , 2015 , 102, 367-371	1.2	5
78	A Hybrid-Type CVD System for Graphene Growth. <i>Chemical Vapor Deposition</i> , 2015 , 21, 176-180		1

77	Unusual thermopower of inhomogeneous graphene grown by chemical vapor deposition. <i>Applied Physics Letters</i> , 2014 , 104, 021902	3.4	12
76	Control of the Dirac point in graphene by UV light. <i>JETP Letters</i> , 2014 , 98, 704-708	1.2	6
75	Detection of graphene microelectromechanical system resonance. <i>Journal of Applied Physics</i> , 2014 , 116, 224510	2.5	
74	Growth mechanism of graphene on platinum: Surface catalysis and carbon segregation. <i>Applied Physics Letters</i> , 2014 , 104, 152107	3.4	43
73	Influence of graphene synthesizing techniques on the photocatalytic performance of graphene-TiO ₂ nanocomposites. <i>Physical Chemistry Chemical Physics</i> , 2013 , 15, 15528-37	3.6	37
72	Frame assisted H ₂ O electrolysis induced H ₂ bubbling transfer of large area graphene grown by chemical vapor deposition on Cu. <i>Applied Physics Letters</i> , 2013 , 102, 022101	3.4	91
71	Quantum Hall effect in graphene decorated with disordered multilayer patches. <i>Applied Physics Letters</i> , 2013 , 103, 233110	3.4	24
70	Metal-Free Graphene as Transparent Electrode for GaN-Based Light-Emitters. <i>Japanese Journal of Applied Physics</i> , 2013 , 52, 08JG05	1.4	2
69	Microwave characterization of Ti/Au-graphene contacts. <i>Applied Physics Letters</i> , 2013 , 103, 173111	3.4	3
68	Towards transfer-free fabrication of graphene NEMS grown by chemical vapour deposition. <i>Micro and Nano Letters</i> , 2012 , 7, 749	0.9	6
67	Chemical vapor deposition of nanocrystalline graphene directly on arbitrary high-temperature insulating substrates 2012 ,		1
66	Low Partial Pressure Chemical Vapor Deposition of Graphene on Copper. <i>IEEE Nanotechnology Magazine</i> , 2012 , 11, 255-260	2.6	49
65	Graphene conductance uniformity mapping. <i>Nano Letters</i> , 2012 , 12, 5074-81	11.5	112
64	Direct Chemical Vapor Deposition of Large-Area Carbon Thin Films on Gallium Nitride for Transparent Electrodes: A First Attempt. <i>IEEE Transactions on Semiconductor Manufacturing</i> , 2012 , 25, 494-501	2.6	20
63	Transfer-free fabrication of suspended graphene grown by chemical vapor deposition 2012 ,		3
62	The Aharonov-Bohm effect in graphene rings with metal mirrors. <i>Carbon</i> , 2012 , 50, 5562-5568	10.4	9
61	Cleaning graphene using atomic force microscope. <i>Journal of Applied Physics</i> , 2012 , 111, 064904	2.5	51
60	Controllable chemical vapor deposition of large area uniform nanocrystalline graphene directly on silicon dioxide. <i>Journal of Applied Physics</i> , 2012 , 111, 044103	2.5	46

59	Graphene p-n junctions controlled by local gates made of naturally oxidized thin aluminium films. <i>Carbon</i> , 2012 , 50, 1987-1992	10.4	15
58	Noncatalytic chemical vapor deposition of graphene on high-temperature substrates for transparent electrodes. <i>Applied Physics Letters</i> , 2012 , 100, 022102	3.4	61
57	Large-area uniform graphene-like thin films grown by chemical vapor deposition directly on silicon nitride. <i>Applied Physics Letters</i> , 2011 , 98, 252107	3.4	72
56	Family of graphene-based superconducting devices. <i>JETP Letters</i> , 2011 , 94, 329-332	1.2	6
55	Temperature distribution in a large Bi ₂ Sr ₂ CaCu ₂ O _{8+x} mesa. <i>Physical Review B</i> , 2011 , 83,	3.3	75
54	Temperature distribution in a stack of intrinsic Josephson junctions with their CuO-plane electrodes oriented perpendicular to supporting substrate. <i>Superconductor Science and Technology</i> , 2011 , 24, 015003	3.1	14
53	In situ detection of radiation and heat balance in large Bi ₂ 212 mesas. <i>Physica C: Superconductivity and Its Applications</i> , 2010 , 470, 818-821	1.3	3
52	Intrinsic Josephson Tunneling in High-Temperature Superconductors. <i>Nanoscience and Technology</i> , 2010 , 137-161	0.6	
51	Small-number arrays of intrinsic Josephson junctions. <i>Physica C: Superconductivity and Its Applications</i> , 2008 , 468, 674-678	1.3	7
50	Intrinsic Josephson junctions in mesas and ultrathin BSCCO single crystals: Ultimate control of shape and dimensions. <i>Physica C: Superconductivity and Its Applications</i> , 2007 , 460-462, 316-319	1.3	
49	Intrinsic Josephson junctions formed inside ultra-thin BSCCO single crystals. <i>Superconductor Science and Technology</i> , 2007 , 20, S28-S33	3.1	2
48	Self-consistent estimations of heating in stacks of intrinsic Josephson junctions. <i>Superconductor Science and Technology</i> , 2007 , 20, S48-S53	3.1	6
47	Current-induced in-plane superconducting transition in intrinsic Josephson junctions. <i>Superconductor Science and Technology</i> , 2006 , 19, S209-S212	3.1	3
46	Thickness dependence of the superconducting properties of ultra-thin Bi ₂ Sr ₂ CaCu ₂ O _{8+x} single crystals. <i>Superconductor Science and Technology</i> , 2006 , 19, S205-S208	3.1	6
45	Single intrinsic Josephson junction with double-sided fabrication technique. <i>Applied Physics Letters</i> , 2006 , 88, 222501	3.4	18
44	Superconducting critical current of a single Cu ₂ O ₄ plane in a Bi ₂ Sr ₂ CaCu ₂ O _{8+x} single crystal. <i>Physical Review B</i> , 2005 , 71,	3.3	22
43	Superconducting properties of ultrathin Bi ₂ Sr ₂ CaCu ₂ O _{8+x} single crystals. <i>Journal of Applied Physics</i> , 2005 , 98, 033913	2.5	13
42	Yurgens et al. Reply:. <i>Physical Review Letters</i> , 2004 , 92,	7.4	31

41	Intrinsic Josephson junctions in a magnetic field. <i>Physica C: Superconductivity and Its Applications</i> , 2004 , 404, 431-439	1.3	
40	Intrinsic tunneling spectra of Bi ₂ (Sr _{2-x} La _x)CuO _{6+δ} . <i>Physical Review Letters</i> , 2003 , 90, 147005	7.4	58
39	Intrinsic tunneling in high-T _c Bi ₂ 212 crystals supports a coexistence of superconducting and pseudo-gaps. <i>Physica C: Superconductivity and Its Applications</i> , 2001 , 352, 89-94	1.3	7
38	Pseudogap features of intrinsic tunneling in Bi ₂ 212 single crystals. <i>Physica C: Superconductivity and Its Applications</i> , 2001 , 362, 286-289	1.3	9
37	Intrinsic Josephson tunneling for basic studies of high-temperature superconductors. <i>Current Applied Physics</i> , 2001 , 1, 413-417	2.6	1
36	Fabrication of Bi ₂ /Sr ₂ /CaCu ₂ /O _{8+δ} films and intrinsic Josephson junctions. <i>IEEE Transactions on Applied Superconductivity</i> , 2001 , 11, 2703-2706	1.8	1
35	Self-heating in small mesa structures. <i>Journal of Applied Physics</i> , 2001 , 89, 5578-5580	2.5	55
34	Magnetic field dependence of the superconducting gap and the pseudogap in Bi ₂ 212 and HgBr ₂ -Bi ₂ 212, studied by intrinsic tunneling spectroscopy. <i>Physical Review Letters</i> , 2001 , 86, 2657-60	7.4	126
33	Flux-flow branches and Fiske steps in Bi-2212 mesas. <i>Physica B: Condensed Matter</i> , 2000 , 284-288, 1856-1857	1.8	4
32	Intrinsic Josephson junctions for studies of high-T _c superconductors. <i>Physica C: Superconductivity and Its Applications</i> , 2000 , 341-348, 2277-2280	1.3	3
31	Intrinsic Josephson junctions: recent developments. <i>Superconductor Science and Technology</i> , 2000 , 13, R85-R100	3.1	142
30	Comparison of Josephson fluxon modes in high- and low-temperature superconducting stacked Josephson junctions. <i>Physical Review B</i> , 2000 , 61, 766-777	3.3	26
29	Evidence for coexistence of the superconducting gap and the pseudogap in Bi-2212 from intrinsic tunneling spectroscopy. <i>Physical Review Letters</i> , 2000 , 84, 5860-3	7.4	289
28	Intrinsic Josephson effects in submicrometre Bi ₂ 212 mesas fabricated by using focused ion beam etching. <i>Superconductor Science and Technology</i> , 1999 , 12, 1013-1015	3.1	6
27	Multiple flux-flow branches and phase transition of Josephson fluxon lattice in intrinsic Bi ₂ /Sr ₂ /CaCu ₂ /O _{8+x} stacked Josephson junctions. <i>IEEE Transactions on Applied Superconductivity</i> , 1999 , 9, 4499-4502	1.8	2
26	Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} Intrinsic Josephson junctions in a magnetic field. <i>Physical Review B</i> , 1999 , 59, 7196-7204	3.3	42
25	Partial filling of columnar defects by vortices as seen in measurements of the c-axis critical current of Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} <i>Physical Review B</i> , 1999 , 60, 12480-12484	3.3	11
24	Interlayer Coupling and Superconducting Critical Temperature of Bi ₂ Sr _{1.5} La _{0.5} CuO _{6+δ} and Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} Incommensurate Effects of Pressure. <i>Physical Review Letters</i> , 1999 , 82, 3148-3151	7.4	17

23	EFFECT OF PRESSURE ON INTERLAYER COUPLING AND SUPERCONDUCTING TRANSITION TEMPERATURE OF Bi-2201 AND Bi-2212. <i>International Journal of Modern Physics B</i> , 1999 , 13, 3744-3746	1.1	1
22	Fluxon modes in stacked HTSC intrinsic Josephson junctions. <i>Applied Superconductivity</i> , 1999 , 6, 777-782		2
21	Effect of Pressure on the Out-of-Plane Critical Current and T _c of Bi-2201 and Bi-2212 Single Crystals. <i>Journal of Low Temperature Physics</i> , 1999 , 117, 1211-1215	1.3	1
20	Fiske steps in intrinsic Bi ₂ Sr ₂ CaCu ₂ O _{8+x} stacked Josephson junctions. <i>Physical Review B</i> , 1999 , 59, 8463-8466	3.3	79
19	PSEUDO-GAP FEATURES OF INTRINSIC TUNNELING IN (HgBr ₂)-Bi2212 SINGLE CRYSTALS. <i>International Journal of Modern Physics B</i> , 1999 , 13, 3758-3763	1.1	55
18	Magnetic field dependence of the critical current in stacked Josephson junctions. Evidence for fluxon modes in Bi ₂ Sr ₂ CaCu ₂ O _{8+x} mesas. <i>Physica C: Superconductivity and Its Applications</i> , 1998 , 304, 172-178	1.3	13
17	Multiple-valued c-axis critical current and phase locking in Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} single crystals. <i>Physical Review B</i> , 1998 , 57, R8135-R8138	3.3	44
16	Observation of normal and superconducting state energy gap features from intrinsic c-axis interlayer tunneling in Bi ₂ Sr ₂ CaCu ₂ O ₈ crystals 1998 , 3480, 11		3
15	In situ controlled fabrication of stacks of high-T _c intrinsic Josephson junctions. <i>Applied Physics Letters</i> , 1997 , 70, 1760-1762	3.4	55
14	Relationship between the Out-Of-Plane Resistance and the Subgap Resistance of Intrinsic Josephson Junctions in Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} <i>Physical Review Letters</i> , 1997 , 79, 5122-5125	7.4	50
13	C-axis magnetoresistance of a few atomic surface layers of the Bi:2212 single crystals. <i>Physica C: Superconductivity and Its Applications</i> , 1997 , 282-287, 2293-2294	1.3	1
12	The c-axis gap parameter and resistivity of an individual intrinsic tunnel junction in Bi-2212 single crystals. <i>Physica C: Superconductivity and Its Applications</i> , 1997 , 293, 181-185	1.3	1
11	Gap and sub-gap structures of intrinsic Josephson tunnel junctions in Bi ₂ Sr ₂ CaCu ₂ O _{8+x} single crystals 1996 ,		21
10	Peak in the temperature dependence of the c-axis Josephson current in Bi ₂ Sr ₂ CaCu ₂ O _{8+x} intrinsic Josephson junctions. <i>European Physical Journal D</i> , 1996 , 46, 1273-1274		3
9	Intrinsic Josephson junctions in Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} single crystals. <i>European Physical Journal D</i> , 1996 , 46, 1293-1294		1
8	Strong temperature dependence of the c-axis gap parameter of Bi ₂ Sr ₂ CaCu ₂ O _{8+δ} intrinsic Josephson junctions. <i>Physical Review B</i> , 1996 , 53, R8887-R8890	3.3	130
7	Intrinsic Josephson tunnel junctions fabricated on the surfaces of Bi2212 single crystals by photolithography. <i>Physica C: Superconductivity and Its Applications</i> , 1994 , 235-240, 3269-3270	1.3	34
6	Vortex motion under the influence of a temperature gradient. <i>Physical Review B</i> , 1992 , 46, 6643-6646	3.3	27

5	Optically induced magnetic relaxation in Bi-2212 single crystals. <i>Physica C: Superconductivity and Its Applications</i> , 1992 , 203, 277-283	1.3	9
4	Transport coefficients and flux motion in Bi ₂ Sr ₂ CaCu ₂ O _x single crystals. <i>Physica C: Superconductivity and Its Applications</i> , 1991 , 180, 417-425	1.3	76
3	Mixed state properties of Bi ₂ Sr ₂ CaCu ₂ O _x single crystals with T _c 95 K. <i>Physica C: Superconductivity and Its Applications</i> , 1991 , 185-189, 1817-1818	1.3	4
2	Transport properties of Bi ₂ Sr ₂ CaCu ₂ O _x single crystals with T _c =95 K. <i>Physica C: Superconductivity and Its Applications</i> , 1990 , 169, 174-178	1.3	23
1	Phonon transport phenomena in high-T _c superconductors. <i>Physica C: Superconductivity and Its Applications</i> , 1989 , 162-164, 562-563	1.3	3